

Docket No. 241473US2

IN RE APPLICATION OF: Hiroaki HAZAMA

SERIAL NO: 10/639,443

FILED: August 13, 2003

FOR: A SEMICONDUCTOR MEMORY DEVICE HAVING A MULTI-LAYERED INTERLAYER INSULATION  
CONSISTING OF DEUTERIUM AND NITRIDE



IPW

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Transmitted herewith is an amendment in the above-identified application.

☒ No additional fee is required

☐ Small entity status of this application under 37 C.F.R. §1.9 and §1.27 is claimed.

☐ Additional documents filed herewith:

The Fee has been calculated as shown below:

CLAIMS	CLAIMS REMAINING		HIGHEST NUMBER PREVIOUSLY PAID	NO. EXTRA CLAIMS	RATE	CALCULATIONS
TOTAL	28	MINUS	33	0	x \$50 =	\$0.00
INDEPENDENT	2	MINUS	3	0	x \$200 =	\$0.00
		<input type="checkbox"/> MULTIPLE DEPENDENT CLAIMS			+ \$360 =	\$0.00
		TOTAL OF ABOVE CALCULATIONS				\$0.00
		<input type="checkbox"/> Reduction by 50% for filing by Small Entity				\$0.00
		<input type="checkbox"/> Recordation of Assignment			+ \$40 =	\$0.00
		TOTAL				\$0.00

☐ A check in the amount of \$0.00 is attached.

☐ Credit card payment form is attached to cover the fees in the amount of \$0.00

☒ Please charge any additional Fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

☒ If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time may be charged to Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

OBLON, SPIVAK, McCLELLAND,  
MAIER & NEUSTADT, P.C.

Eckhard H. Kuesters

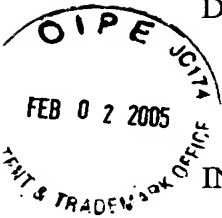
Registration No. 28,870

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DOCKET NO: 241473US2



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

:

HIROAKI HAZAMA

: EXAMINER: ABRAHAM, F.

SERIAL NO: 10/639,443

:

FILED: AUGUST 13, 2003

: GROUP ART UNIT: 2826

FOR: A SEMICONDUCTOR MEMORY  
DEVICE HAVING A MULTI-LAYERED  
INTERLAYER INSULATION  
CONSISTING OF DEUTERIUM AND  
NITRIDE

:

AMENDMENT UNDER 37 C.F.R. §1.312

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to patent issuance, please amend the above-identified application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on  
page 2 of this paper.

**Remarks** begin on page 7 of this paper.